







SN54AHC240, SN74AHC240

SNx4AHC240 Octal Buffers/Drivers With 3-State Outputs

1 Features

- Low delay, 4.3ns typ. (25°C, 5V)
- Latch-up performance exceeds 250mA per JESD 17

2 Applications

- · Handset: smartphone
- · Network switch
- · Health fitness and wearables

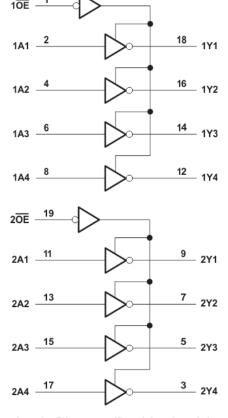
3 Description

These octal buffers/drivers are designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and busoriented receivers and transmitters.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)				
	J (CDIP, 20)	24.2mm x 7.62mm	24.2mm x 6.92mm				
SN54AHC240	W (CFP, 20)	13.09mm x 8.13mm	13.09mm x 6.92mm				
	FK (LCCC, 20)	8.89 mm × 8.89 mm	8.89 mm × 8.89 mm				
	N (PDIP, 20)	24.33mm x 9.4mm	25.40mm x 6.35mm				
SN74AHC240	DW (SOIC, 20)	12.80mm × 10.3mm	12.8mm x 7.5mm				
3N74AHC240	NS (SOP, 20)	12.60mm x 7.8mm	12.6mm x 5.30mm				
	PW (TSSOP, 20)	6.50mm × 6.4mm	6.50mm x 4.40mm				

- (1) For more information, see Section 11.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) The body size (length × width) is a nominal value and does not include pins..



Logic Diagram (Positive Logic)



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4 Pin Configuration and Functions

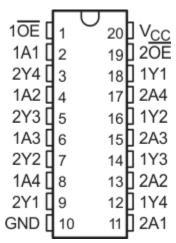


Figure 4-1. SN74AHC240-Q1 PW Package (Top View)

P	IN	- TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	ITPE(")	DESCRIPTION
10E	1	0	Output enable 1
1A1	2	I	1A1 input
2Y4	3	0	2Y4 output
1A2	4	I	1A2 input
2Y3	5	0	2Y3 output
1A3	6	I	1A3 input
2Y2	7	0	2Y2 output
1A4	8	I	1A4 input
2Y1	9	0	2Y1 output
GND	10	G	Ground pin
2A1	11	I	2A1 input
1Y4	12	0	1Y4 output
2A2	13	I	2A2 input
1Y3	14	0	1Y3 output
2A3	15	I	2A3 input
1Y2	16	0	1Y2 output
2A4	17	I	2A4 input
1Y1	18	0	1Y1 output
20E	19	0	Output enable 2
VCC	20	Р	Power pin

⁽¹⁾ Signal Types: I = Input, O = Output, I/O = Input or Output



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any outp	ut in the high-impedance or power-off state ⁽²⁾	-0.5	7	V
Vo	Output voltage range ⁽²⁾	Output voltage range ⁽²⁾			V
I _{IK}	Input clamp current	V _I < -0.5V		-20	mA
I _{OK}	Output clamp current	$V_{O} < -0.5 V \text{ or } V_{O} > V_{CC+} 0.5 V$		±20	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±25	mA
	Continuous output current through V _{CC} or GND			±75	mA
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If briefly operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

Specification	Description	Condition	MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
		V _{CC} = 2V	1.5		
V_{IH}	High-level input voltage	V _{CC} = 3V	2.1		V
		V _{CC} = 5.5V	3.85		
	Low-Level input voltage	V _{CC} = 2V		0.5	
V _{IL}	Low-Level input voltage	V _{CC} = 3V		0.9	V
	Low-Level input voltage	V _{CC} = 5.5V		1.65	
VI	Input Voltage	0	5.5	V	
V _O	Output Voltage	0	V _{CC}	V	
		V _{CC} = 2V		-50	μA
I _{OH}	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4	mA
		$V_{CC} = 5V \pm 0.5V$		-8	mA
		V _{CC} = 2V		50	μΑ
I _{OL}	Low-level output current	$V_{CC} = 3.3V \pm 0.3V$		4	mA
		$V_{CC} = 5V \pm 0.5V$		8	mA
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		100	ns/V
ΔυΔν	Input transition rise or fall rate	$V_{CC} = 5V \pm 0.5V$		20	ns/V
T _A	Operating free-air temperature	•	-40	125	°C

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Thermal Information

	THERMAL METRIC ⁽¹⁾		DB	DGV	N	NS	PW	UNIT
THERMAL METRIC		20 PINS					ONT	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽²⁾	81.1	70	92	69	60	116.8	°C/W

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The package thermal impedance is calculated in accordance with JESD 51-7.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A :	= 25°C		-40°C	to 125°0	3	UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	TYP	MAX	UNII
	I _{OH} = -50μA	2V to 5.5V	V _{CC} -0.1	V _{CC}		V _{CC} -0.1	V _{CC}		
V _{OH}	I _{OH} = −4mA	3V	2.58			2.48			V
	I _{OH} = -8mA	4.5V	3.94			3.8			
	I _{OL} = 50μA	2V to 5.5V			0.1			0.1	
V _{OL}	I _{OL} = 4mA	3V			0.36			0.44	V
	I _{OL} = 8mA	4.5V			0.36			0.44	
II	V_I = 5.5V or GND and V_{CC} = 0V to 5.5V	0V to 5.5V			±0.1			±1	μΑ
loz	$V_O = V_{CC}$ or GND and V_{CC} = 5.5V	5.5V			±0.25			±5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$, and $V_{CC} = 5.5V$	5.5V			4			40	μΑ
Cı	V _I = V _{CC} or GND	5V		2	10			10	pF
Co	Vo = V _{CC} or GND	5V		5					pF
C _{PD}	No load, F = 1MHz	5V		15					pF

5.6 Switching Characteristics

 C_L = 50pF; over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted). See Parameter Measurement Information

PARAMETER	FROM	то	LOAD	V	TA	= 25°C		-40°0	C to 125°C	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	V _{cc}	MIN	TYP	MAX	MIN	TYP MAX	UNII		
t _{PLH}	A	Υ	C _L = 15pF	2V			19.5	1	23	ns		
t _{PHL}		Y	CL = 15pr	2 V			19.5	1	23	ns		
t _{PZH}	- OE	ŌĒ Y	C _L = 15pF	2V			25.5	1	30	ns		
t _{PZL}	OL	1	О[– ТЭРГ	2 V			25.5	1	30	ns		
t _{PHZ}	ŌĒ	Y C _L = 15pF 2\	C = 15×5	2)./			25.5	1	30	ns		
t _{PLZ}			'	C _L = 15pr 2v	O _L = 15με 2	GL - 19pr	2 V			25.5	1	30
t _{PLH}	A	Υ	C _L = 15pF	: 15pF 3.3V		5.3	7.5	1	9	ns		
t _{PHL}		1				5.3	7.5	1	9	ns		
t _{PZH}	- ŌĒ	Υ	C _L = 15pF	3.3V		6.6	10.6	1	12.5	ns		
t _{PZL}	OL	1	О[– ТЭРГ	3.3V		6.6	10.6	1	12.5	ns		
t _{PHZ}	- OE	OE Y C ₁ = 15pF 3.3\	2 21/		7.8	11.5	1	12.5	ns			
t _{PLZ}	JOE	Ī	C _L = 15pF	3.3V		7.8	11.5	1	12.5	ns		
t _{PLH}	A	Υ	C _L = 15pF	5V		3.6	5.5	1	6.5	ns		
t _{PHL}	T T	CL - Topr	30		3.6	5.5	1	6.5	ns			
t _{PZH}	ŌĒ	ŌĒ Y	C _L = 15pF 5V	5\/		4.7	7.3	1	8.5	ns		
t _{PZL}		1		J V		4.7	7.3	1	8.5	ns		



5.6 Switching Characteristics (continued)

 C_L = 50pF; over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted). See *Parameter Measurement Information*

PARAMETER	FROM	то	LOAD	V	TA	= 25°C		-40°0	C to 125°	С	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	V _{cc}	MIN	TYP	MAX	MIN	TYP	MAX	UNII	
t _{PHZ}	- ŌĒ	Υ	C _L = 15pF	5V		5.2	7.2	1		8.5	ns	
t _{PLZ}		T	CL = 15pr	34		5.2	7.2	1		8.5	ns	
t _{PLH}	A	Υ	C _L = 50pF	2V			26.5	1		30	ns	
t _{PHL}		'	О[– 30рі	2 V			26.5	1		30	ns	
t _{PZH}	- ŌĒ	Υ	C _L = 50pF	2V			32.5	1		36.5	ns	
t _{PZL}	OL	'	С[- 30рі	2 V			32.5	1		36.5	ns	
t _{PHZ}	- OE	Υ	C _L = 50pF	2V			32	1		36.5	ns	
t_{PLZ}	OL	'	О[– 30рі	2 V			32	1		36.5	ns	
t _{PLH}	A	Υ	C _L = 50pF	3.3V		7.8	11	1		12.5	ns	
t _{PHL}		'	С[- 30рі	3.5V		7.8	11	1		12.5	ns	
t _{PZH}	- OE	Υ	C _L = 50pF	3.3V		9.1	14.1	1		16	ns	
t _{PZL}	OL	'	С[- 30рі	-L 00p.	3.5V		9.1	14.1	1		16	ns
t _{PHZ}	ŌĒ	Υ	C _L = 50pF	3.3V		10.3	14	1		16	ns	
t _{PLZ}	OL	'	О[– 30рі	J.5V		10.3	14	1		16	ns	
t _{PLH}	A	Υ	C _L = 50pF	5V		5.1	7.5	1		8.5	ns	
t _{PHL}		'	О[- 30рі	JV		5.1	7.5	1		8.5	ns	
t _{PZH}	- OE	Υ	C _L = 50pF	5V		6.2	9.3	1		10.5	ns	
t _{PZL}	OL	'	О[– 30рі	34		6.2	9.3	1		10.5	ns	
t _{PHZ}	ŌĒ	Υ	C _L = 50pF	5V		6.7	9.2	1		10.5	ns	
t _{PLZ}		<u> </u>	OL - John			6.7	9.2	1		10.5	ns	
t _{sk(o)}			C _L = 50pF	2V			2			2	ns	
t _{sk(o)}			C _L = 50pF	3.3V			1.5			1.5	ns	
t _{sk(o)}			C _L = 50pF	5V			1			1	ns	

5.7 Noise Characteristics

VCC = 5V, CL = 50pF, TA = 25°C

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}				V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}				V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}				V
V _{IH(D)}	High-level dynamic input voltage	3.5			V
$V_{IL(D)}$	Low-level dynamic input voltage			1.5	V



5.8 Typical Characteristics

T_A = 25°C (unless otherwise noted)

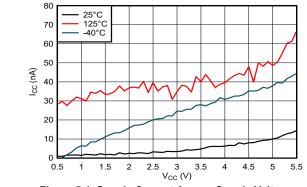


Figure 5-1. Supply Current Across Supply Voltage

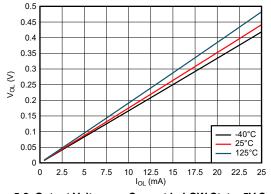


Figure 5-2. Output Voltage vs Current in LOW State; 5V Supply

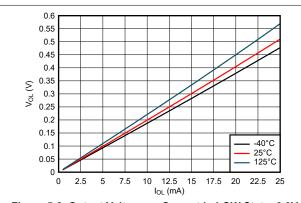


Figure 5-3. Output Voltage vs Current in LOW State; 3.3V Supply

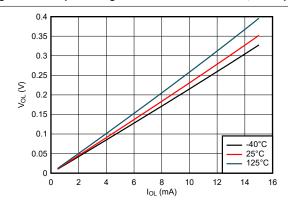
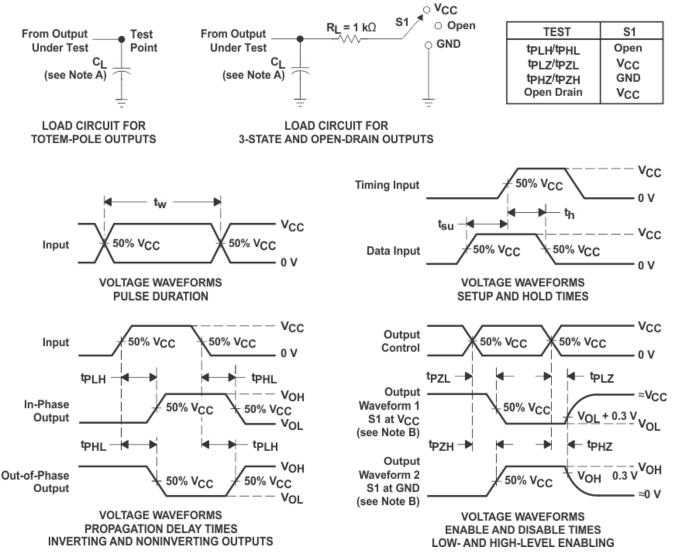


Figure 5-4. Output Voltage vs Current in LOW State; 2.5V Supply



6 Parameter Measurement Information



- A. C_L includes probe and jig capacitance
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1MHz, $Z_O = 50\Omega$, $t_r \leq$ 3ns, $t_f \leq$ 3ns.
- D. The outputs are measured one at a time with one input transition per measurement. E. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms



7 Detailed Description

7.1 Overview

The SNx4AHC240 devices are organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To place the device in the high-impedance state during power up or power down, tie \overline{OE} to V_{CC} through a pullup resistor; the current-sinking capability of the driver determines the minimum value of the resistor.

7.2 Functional Block Diagram

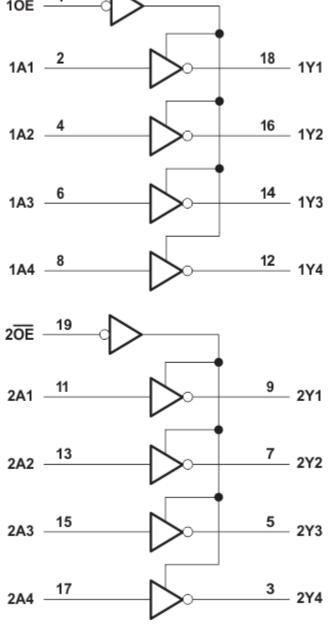


Figure 7-1. Logic Diagram (Positive Logic)



7.3 Feature Description

7.4 Device Functional Modes

Table 7-1. Function Table (Each Buffer)

INPU	OUTPUT ⁽²⁾	
ŌE	A	Y
L	Н	L
L	L	Н
Н	X	Z

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SNx4AHC240 device is a high drive CMOS device that can be used for a multitude of bus-interface type applications where the data needs to be retained or latched. It can produce 24mA of drive current at 3.3V making it ideal for driving multiple outputs and also good for high-speed applications up to 100MHz. The inputs are 5.5V tolerant allowing it to translate down to V_{CC} .

8.2 Typical Application

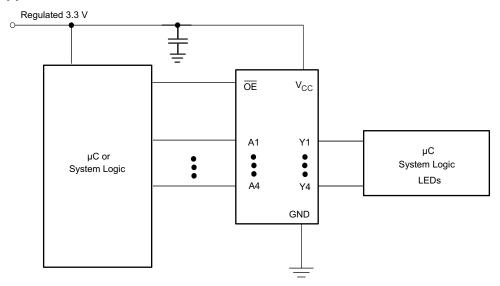


Figure 8-1. Typical Application Diagram

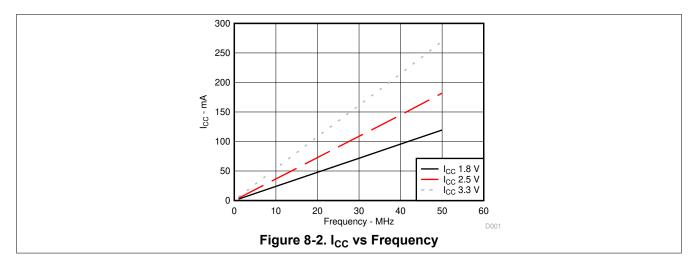
8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5V at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed 25mA per output and 50mA total for the part.
 - Outputs should not be pulled above V_{CC}.

8.2.3 Application Curves



8.3 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in Section 5.3.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends $0.1\mu F$ and if there are multiple V_{CC} terminals, then TI recommends $.01\mu F$ or $.022\mu F$ for each power terminal. It is okay to parallel multiple bypass capacitors to reject different frequencies of noise. A $0.1\mu F$ and $1\mu F$ are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple bit logic devices inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. The following rules specify what must be observed under all circumstances.

All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever makes more sense or is more convenient. It is generally okay to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, then it will disable the outputs section of the part when asserted. This does not disable the input section of the IOs, so they cannot float when disabled.

8.4.2 Layout Example

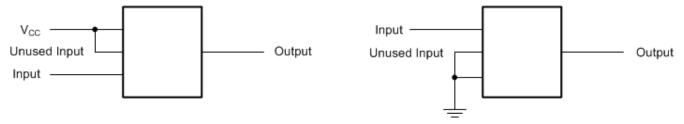


Figure 8-3. Layout Recommendation



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Implications of Slow or Floating CMOS Inputs
- Texas Instruments, Understanding Schmitt Triggers

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-9680701Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9680701Q2A SNJ54AHC 240FK
5962-9680701QRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QR A SNJ54AHC240J
5962-9680701QSA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QS A SNJ54AHC240W
SN74AHC240DGSR	Active	Production	VSSOP (DGS) 20	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SN74AHC240DW	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-40 to 85	AHC240
SN74AHC240DWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SN74AHC240DWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SN74AHC240N	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74AHC240N
SN74AHC240N.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74AHC240N
SN74AHC240NSR	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SN74AHC240NSR.A	Active	Production	SOP (NS) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SN74AHC240PW	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-40 to 85	HA240
SN74AHC240PWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA240
SN74AHC240PWR.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HA240
SN74AHC240RKSR	Active	Production	VQFN (RKS) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AHC240
SNJ54AHC240FK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9680701Q2A SNJ54AHC 240FK
SNJ54AHC240FK.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9680701Q2A SNJ54AHC 240FK
SNJ54AHC240J	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QR A SNJ54AHC240J



8-Nov-2025



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Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SNJ54AHC240J.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QR A SNJ54AHC240J
SNJ54AHC240W	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QS A SNJ54AHC240W
SNJ54AHC240W.A	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9680701QS A SNJ54AHC240W

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

www.ti.com 8-Nov-2025

OTHER QUALIFIED VERSIONS OF SN54AHC240, SN74AHC240:

● Catalog : SN74AHC240

• Automotive : SN74AHC240-Q1, SN74AHC240-Q1

• Military : SN54AHC240

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

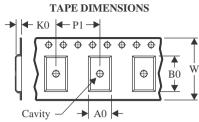
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Jul-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

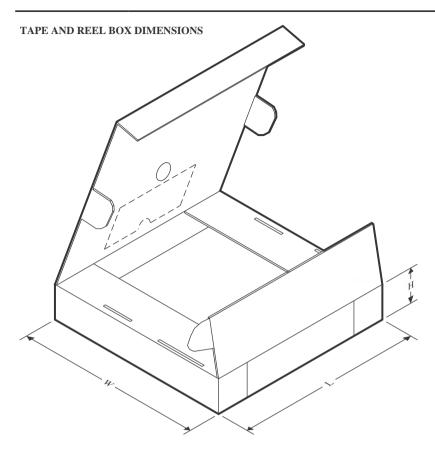


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC240DGSR	VSSOP	DGS	20	5000	330.0	16.4	5.4	5.4	1.45	8.0	16.0	Q1
SN74AHC240DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC240NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHC240PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHC240RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



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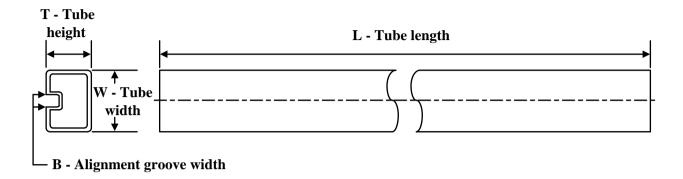
*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC240DGSR	VSSOP	DGS	20	5000	353.0	353.0	32.0
SN74AHC240DWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74AHC240NSR	SOP	NS	20	2000	356.0	356.0	45.0
SN74AHC240PWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74AHC240RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Jul-2025

TUBE

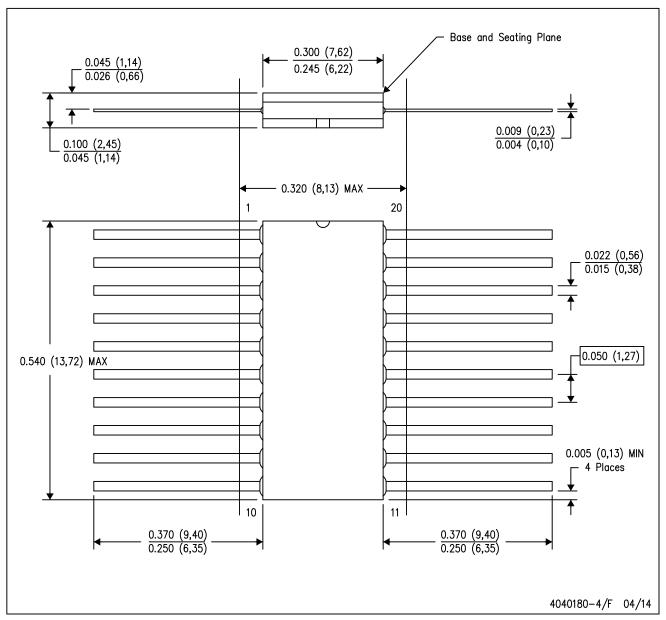


*All dimensions are nominal

All difficultions are nominal								
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9680701Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9680701QSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74AHC240N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AHC240N.A	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54AHC240FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHC240FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHC240W	W	CFP	20	25	506.98	26.16	6220	NA
SNJ54AHC240W.A	W	CFP	20	25	506.98	26.16	6220	NA

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



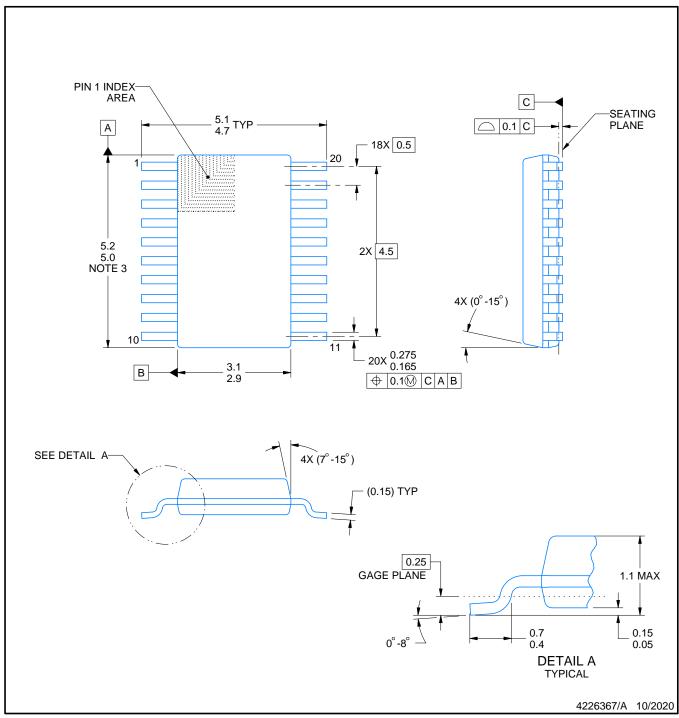


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

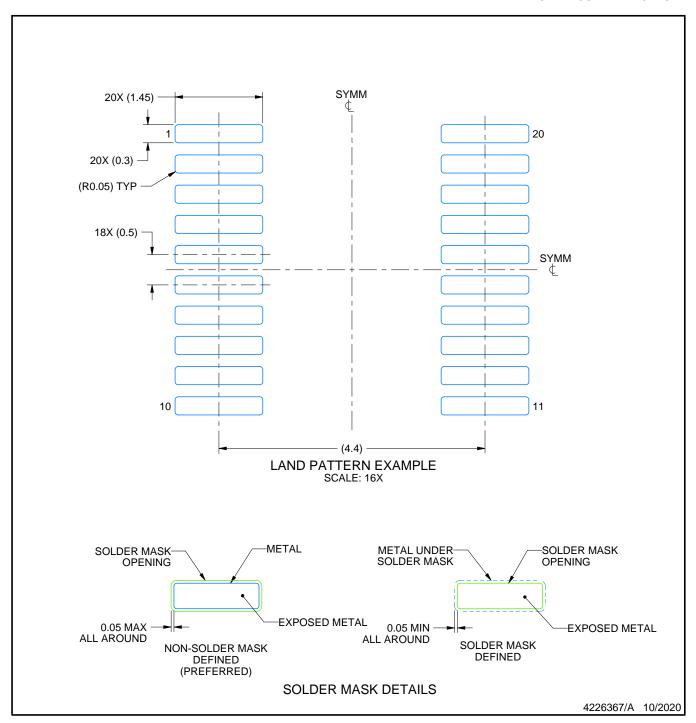
PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. No JEDEC registration as of September 2020.
- 5. Features may differ or may not be present.

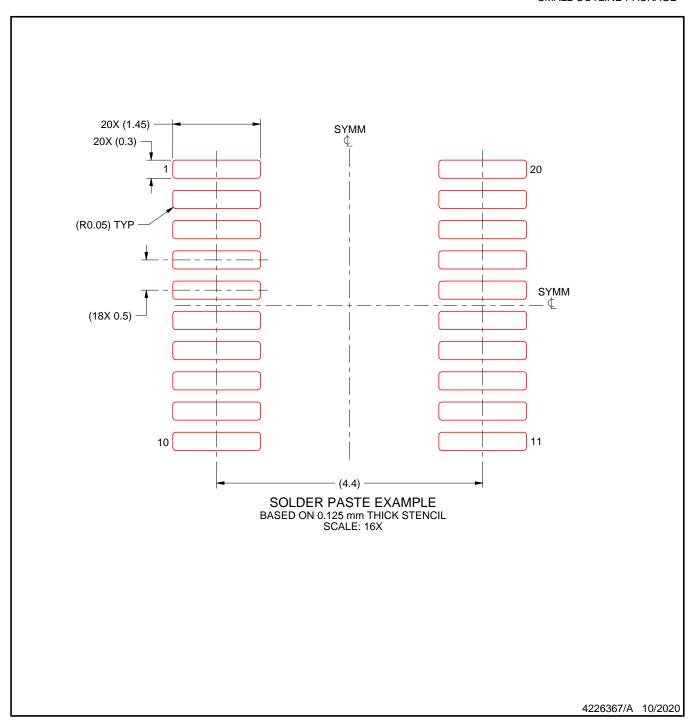




NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)

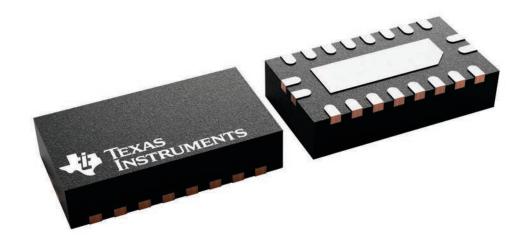
- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



2.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

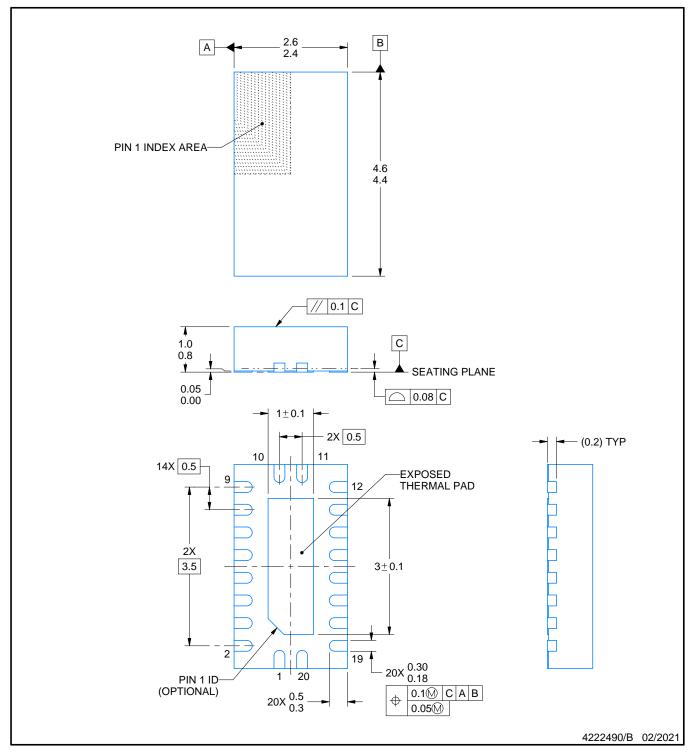
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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PLASTIC QUAD FLATPACK - NO LEAD

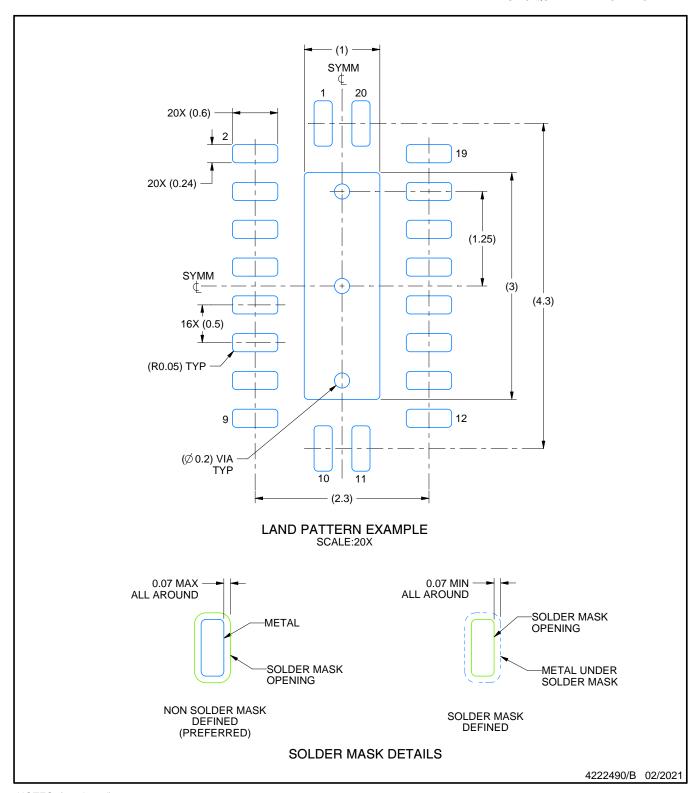


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

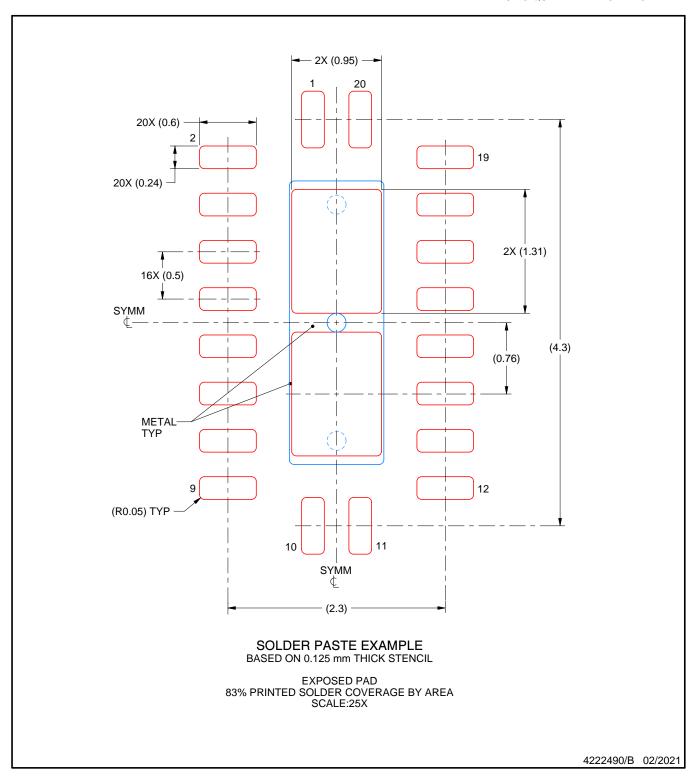


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

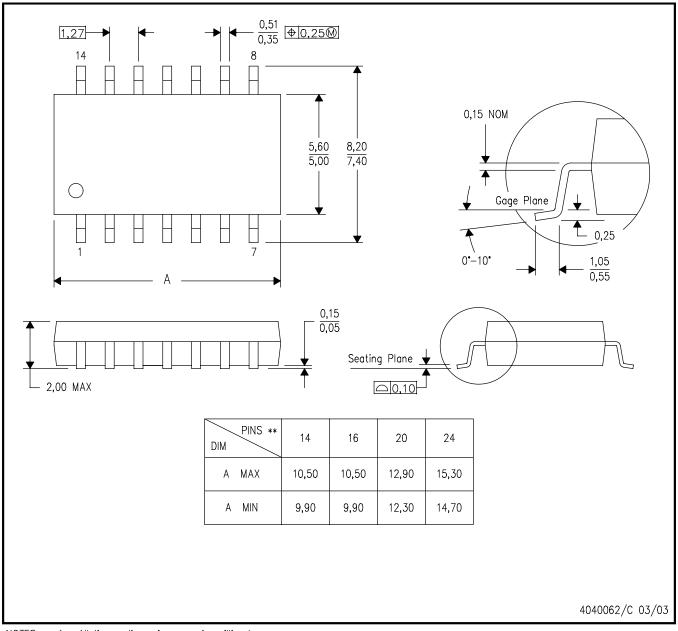


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE

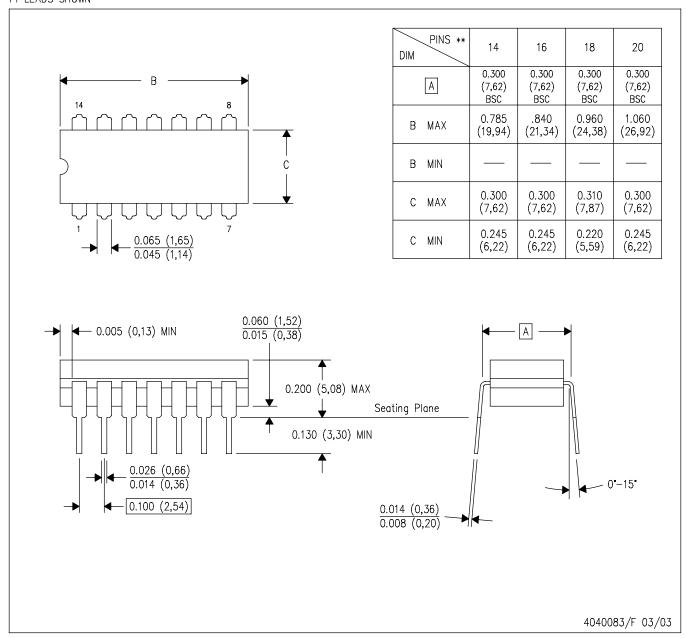


NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



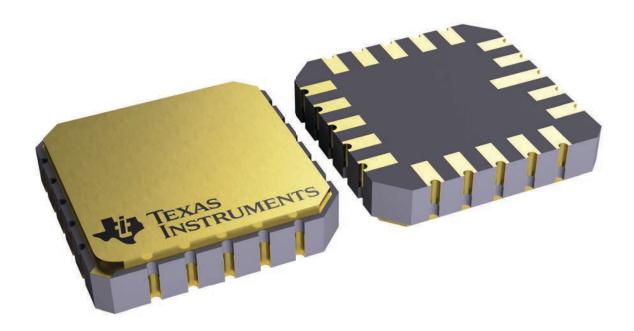
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

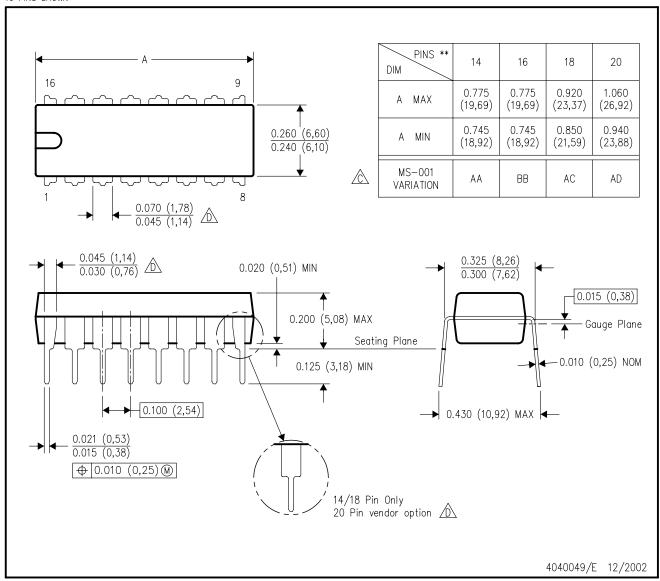


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N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



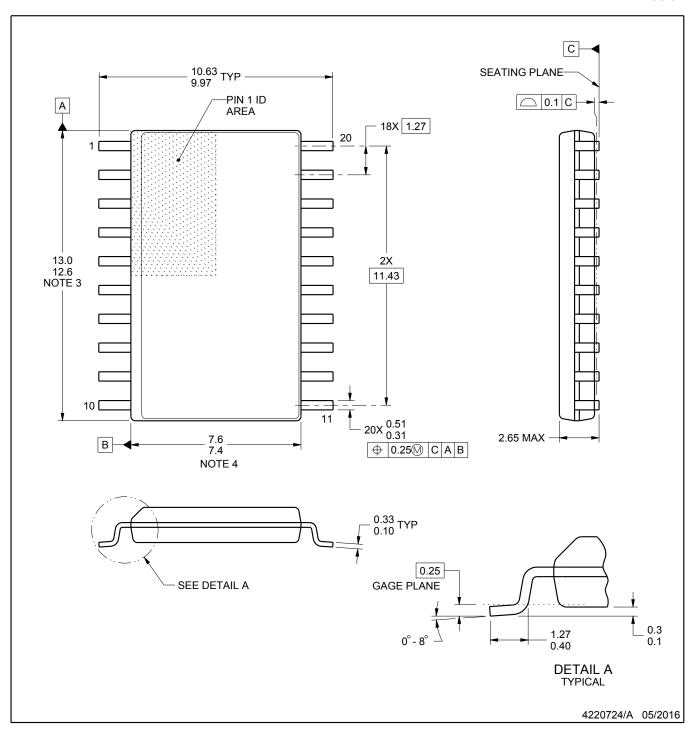
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

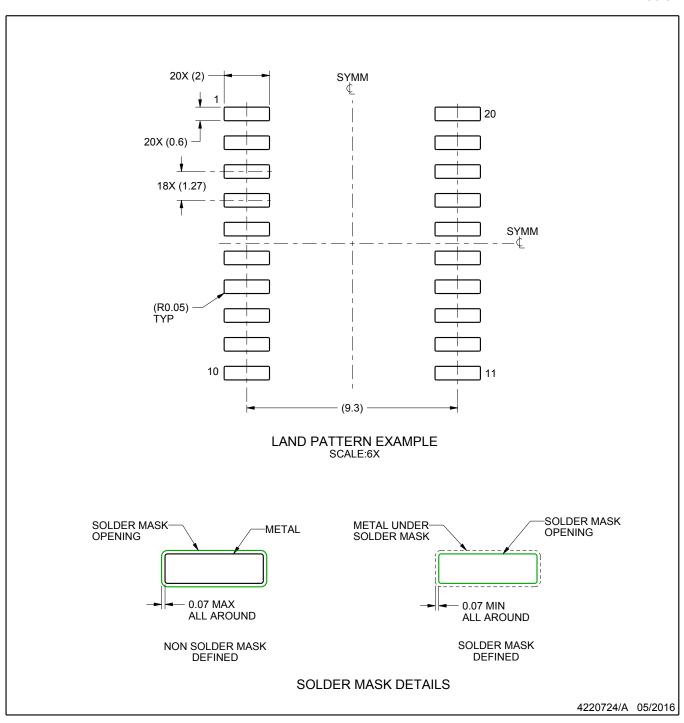
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



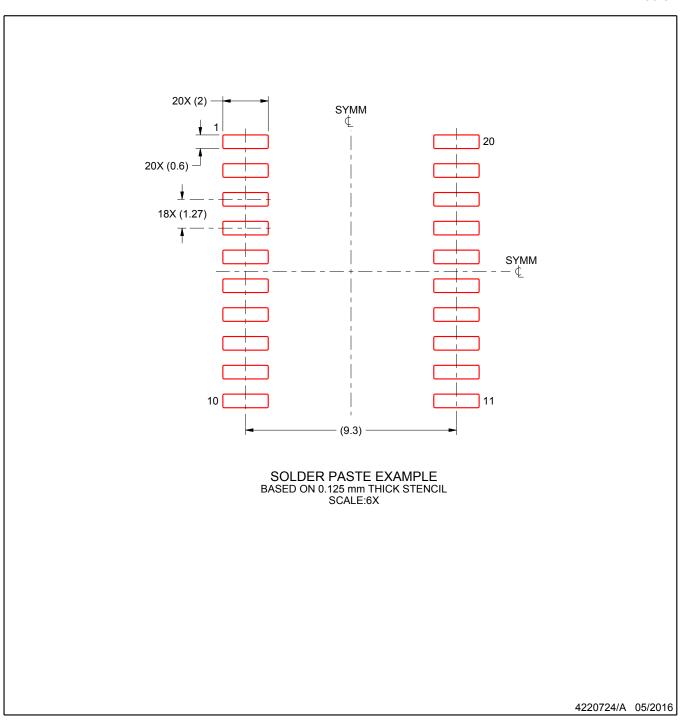
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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